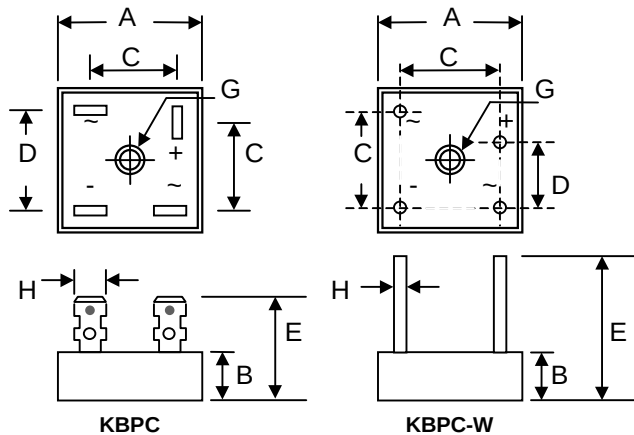


Features

- Diffused Junction
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- Electrically Isolated Metal Case for Maximum Heat Dissipation
- Case to Terminal Isolation Voltage 2500V

Mechanical Data

- Case: KBPC (Metal Case with Faston Lugs) or KBPC-W (Metal Case with Wire Leads)
- Terminals: Plated Faston Lugs or Wire Leads, Add "W" Suffix to Indicate Wire Leads
- Polarity: As Marked on Case
- Mounting: Through Hole with #10 Screw
- Mounting Torque: 23 cm·kg (20 in·lbs) Max.
- Weight: 30 grams (KBPC); 28 grams (KBPC-W)
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version**



	KBPC		KBPC-W	
Dim	Min	Max	Min	Max
A	27.94	28.96	27.94	28.96
B	10.97	11.23	10.97	11.23
C	15.50	17.60	17.10	19.10
D	17.50	18.50	10.90	11.90
E	22.86	25.40	30.50	—
G	Hole for #10 screw, 5.08Ø Nominal			
H	6.35 Typical		0.97Ø	1.07Ø
All Dimension in mm				

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	KBPC50										Unit
		00	01	02	04	06	08	10	12	14	16	
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	1200	1400	1600	V
Working Peak Reverse Voltage	V _{RWM}											
DC Blocking Voltage	V _R											
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	840	980	1120	V
Average Rectified Output Current @T _A = 60°C	I _O	50										A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	450										A
Forward Voltage per leg @I _F = 25A	V _{FM}	1.2										V
Peak Reverse Current @T _C = 25°C	I _{RM}	10										μA
At Rated DC Blocking Voltage @T _C = 125°C		1.0										mA
I ² t Rating for Fusing (t < 8.3ms)	I ² t	800										A ² s
Typical Junction Capacitance (Note 1)	C _j	300										pF
Typical Thermal Resistance per leg (Note 2)	R _{θJC}	1.6										°C/W
RMS Isolation Voltage from Case to Leads	V _{ISO}	2500										V
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150										°C

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance junction to case, mounted on heatsink.

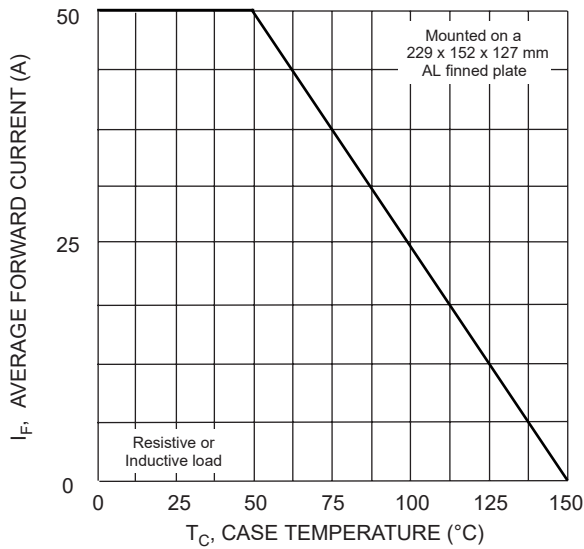


Fig. 1 Forward Current Derating Curve

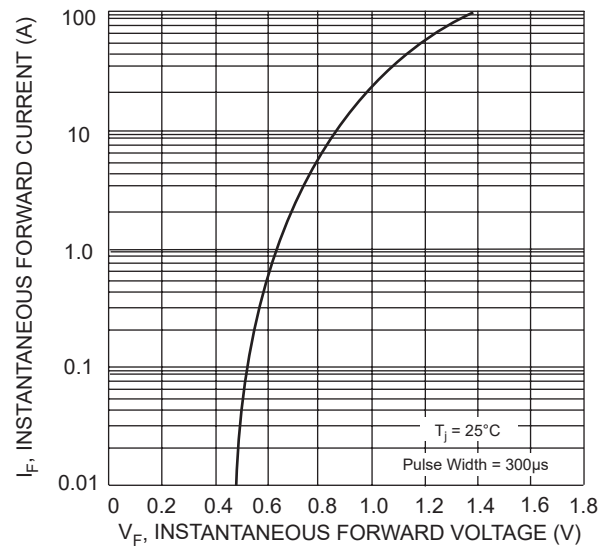


Fig. 2 Typical Forward Characteristics (per element)

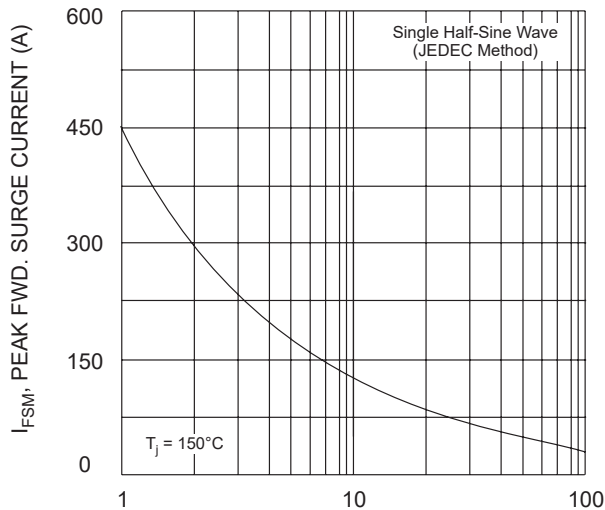


Fig. 3 Max Non-Repetitive Surge Current

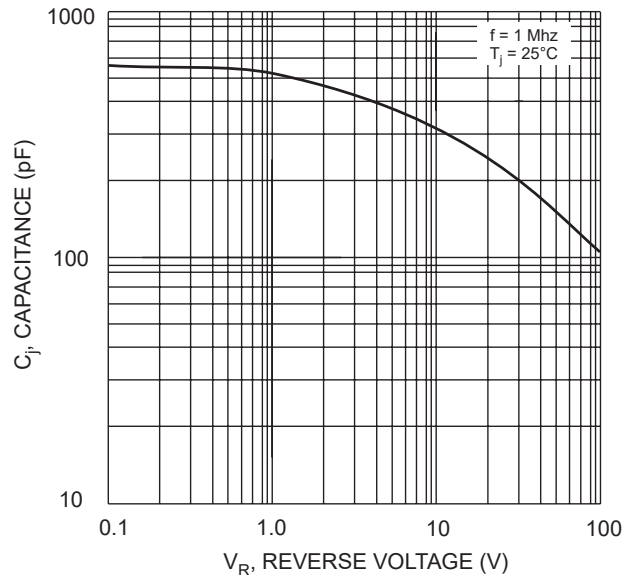


Fig. 4 Typical Junction Capacitance (per element)

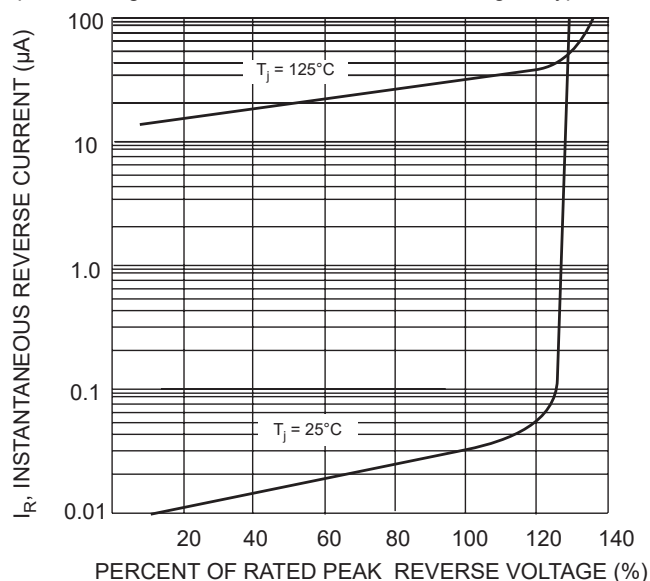


Fig. 5 Typical Reverse Characteristics (per element)